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[Vishay Semiconductor/Diodes Division](#)  
[VS-243NQ100PBF](#)

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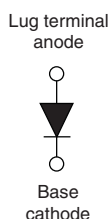
## VS-243NQ100PbF

Vishay Semiconductors

### High Performance Schottky Rectifier, 240 A



HALF-PAK (D-67)



#### FEATURES

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level
- UL approved file E222165
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

PRODUCT SUMMARY	
I <sub>F(AV)</sub>	240 A
V <sub>R</sub>	100 V
Package	HALF-PAK (D-67)
Circuit	Single diode

#### DESCRIPTION

The VS-243NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
I <sub>F(AV)</sub>	Rectangular waveform	240	A
V <sub>RRM</sub>		100	V
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	25 500	A
V <sub>F</sub>	240 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.72	V
T <sub>J</sub>	Range	-55 to +175	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-243NQ100PbF	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	100	V
Maximum working peak reverse voltage	V <sub>RWM</sub>		

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 132 °C, rectangular waveform	240	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	25 500	
		10 ms sine or 6 ms rect. pulse	3300	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 5.5 A, L = 1 mH	15	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 μs Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical	1	A



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	$V_{FM}^{(1)}$	240 A	$T_J = 25\text{ }^\circ\text{C}$	0.95	V
		480 A		1.26	
		240 A	$T_J = 125\text{ }^\circ\text{C}$	0.72	
		480 A		0.85	
Maximum reverse leakage current See fig. 2	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	6	mA
		$T_J = 125\text{ }^\circ\text{C}$		80	
Maximum junction capacitance	$C_T$	$V_R = 5\text{ }V_{DC}$ (test signal range 100 kHz to 1 MHz) $25\text{ }^\circ\text{C}$		5500	pF
Typical series inductance	$L_S$	From top of terminal hole to mounting plane		5.0	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		10 000	V/ $\mu\text{s}$

**Note**

(1) Pulse width = 500  $\mu\text{s}$

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55 to +175	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation See fig. 4	0.19	$^\circ\text{C/W}$
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth and greased	0.05	
Approximate weight			30	g
			1.06	oz.
Mounting torque	minimum	Non-lubricated threads	3 (26.5)	N · m (lbf · in)
	maximum		4 (35.4)	
Terminal torque	minimum		3.4 (30)	
	maximum		5 (44.2)	
Case style			HALF-PAK module	

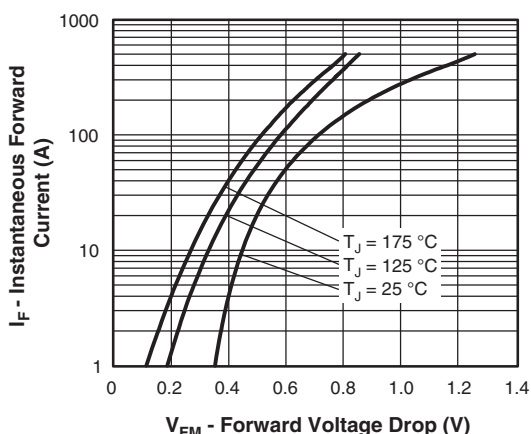


Fig. 1 - Maximum Forward Voltage Drop Characteristics

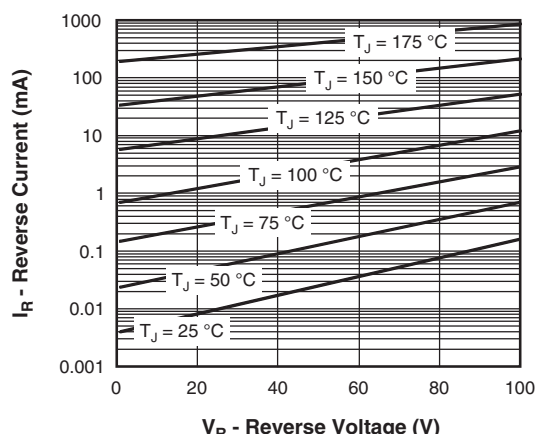


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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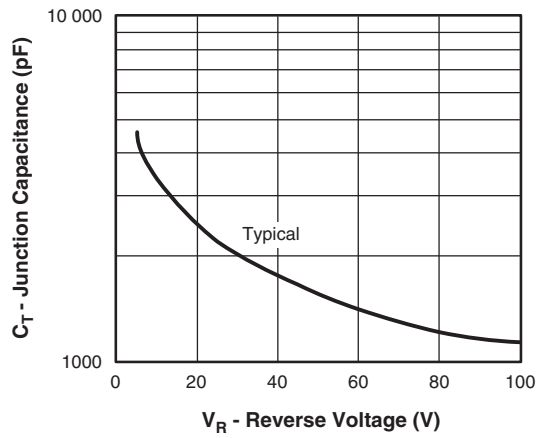


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

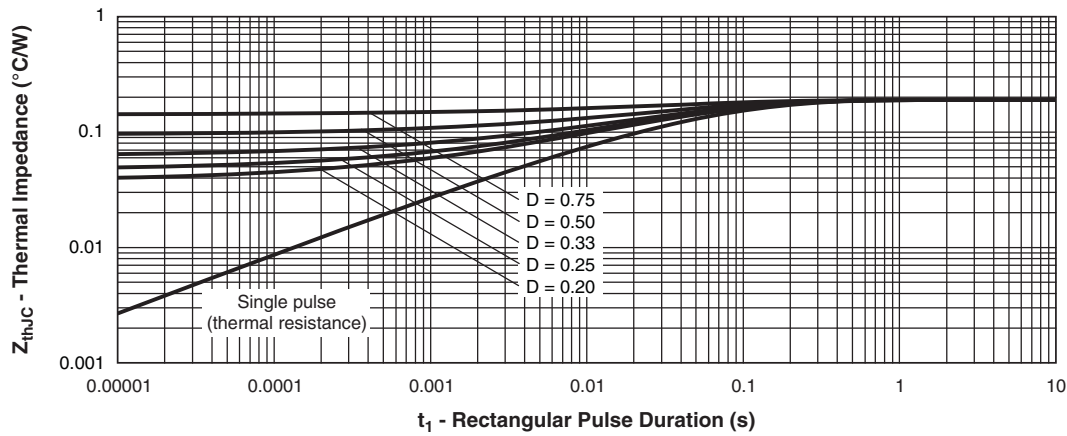


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

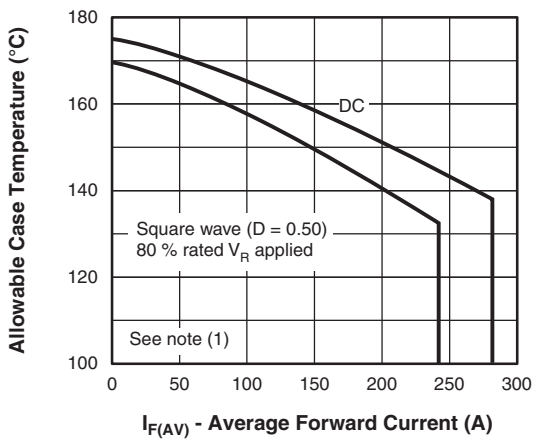


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

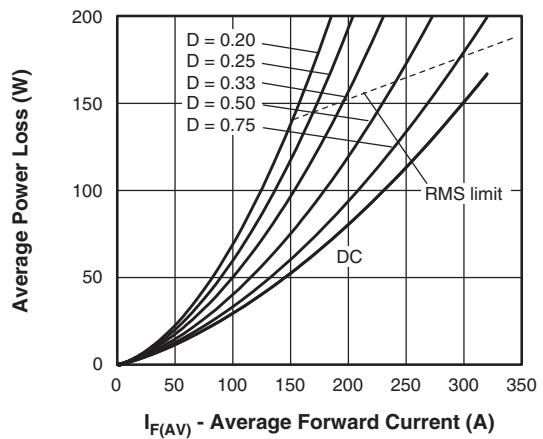


Fig. 6 - Forward Power Loss Characteristics



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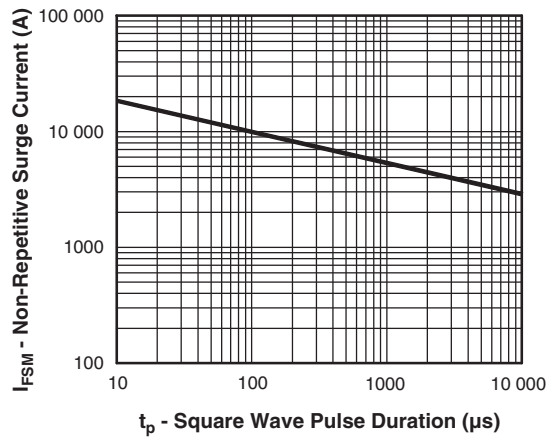


Fig. 7 - Maximum Non-Repetitive Surge Current

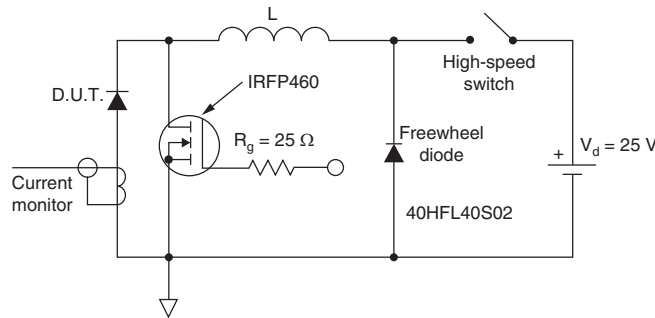


Fig. 8 - Unclamped Inductive Test Circuit

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;
- $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);
- $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$

**ORDERING INFORMATION TABLE**

Device code	<b>VS-</b>	<b>24</b>	<b>3</b>	<b>N</b>	<b>Q</b>	<b>100</b>	<b>PbF</b>
	①	②	③	④	⑤	⑥	⑦

- 1** - Vishay Semiconductors product
- 2** - Average current rating (x 10)
- 3** - Product silicon identification
- 4** - N = Not isolated
- 5** - Q = Schottky rectifier diode
- 6** - Voltage rating (100 = 100 V)
- 7** - Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95020">www.vishay.com/doc?95020</a>

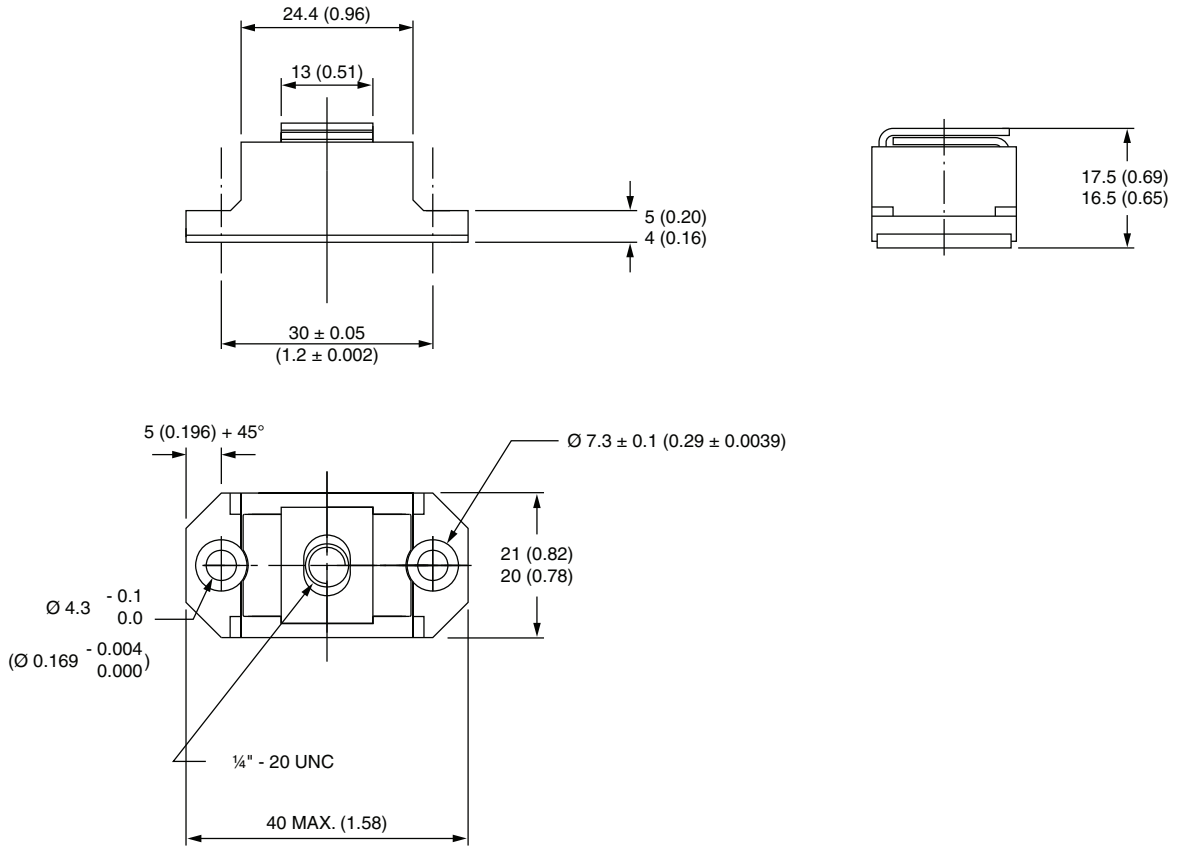


## Outline Dimensions

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### D-67 HALF-PAK

**DIMENSIONS** in millimeters (inches)





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